

600 V, 31.5 A, 105 mΩ

Description

The 600V FRD series has ultra-fast body diode performance, low on-resistance and reduced gate charge.

It combines the benefits of a fast switching performance with ease of usage and robustness. Additionally, we offer low reverse recovery time (trr) and reverse recovery charge (Qrr) for the bridge structure topology, especially for resonant converters (LLC, PSFB, etc.).

Applications

- Soft Switching Topologies
- · Telecom and Sever Power Supplies
- · EV Charger and Industrial Power Supplies

Features

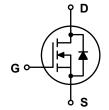
BV _{DSS} @ T _{J,max}	I _D	R _{DS(on),max}	$Q_{g,typ}$
650 V	31.5 A	105 mΩ	53 nC

- Reduced Switching & Conduction Losses
- Fast Recovery Body-Diode
- · Lower Gate Resistance
- 100% Avalanche Tested
- Pb-free and RoHS Compliant
- Compliance with EU REACH









Absolute Maximum Ratings (T_C = 25°C unless otherwise noted)

Symbol	Parameter		Value	Unit	
V _{DSS}	Drain to Source Voltage		600	V	
V _{GSS}	Gate to Source Voltage		±30	V	
		Continuous (T _C = 25°C)	31.5	^	
I _D	Drain Current	Continuous (T _C = 100°C)	19.9	A	
I _{DM}	Drain Current	Pulsed (Note1)	94.5	Α	
E _{AS}	Single Pulsed Avalanche Energy (Note2)		187	mJ	
I _{AS}	Avalanche Current (Note2)		5.4	Α	
E _{AR}	Repetitive Avalanche Energy (Note1)		2.6	mJ	
-1/-14	MOSFET dv/dt		100	\ //	
dv/dt	Peak Diode Recovery dv/dt	(Note3)	50	V/ns	
P _D Pov	D	(T _C = 25°C)	260	W	
	Power Dissipation	Derate Above 25°C	2.08	W/°C	
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to 150	°C	
T _L	Maximum Lead Temperature for Soldering, 1/8" from Case for 10 Seconds		260	°C	

Thermal Characteristics

Symbol	Parameter	Value	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	0.48	°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, Max.	62.5	°C/W



N-Channel Power MOSFET



Package Marking and Ordering Information

Part Number	Top Marking	Package	Packing Method	Quantity
HXMH60M105P	H60M105P	TO-247AB	Tube	30 units

Electrical Characteristics	$(T_C = 25^{\circ}C \text{ unless otherwise noted})$
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Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
Off Chara	cteristics	•	•	•		
D) /	Danier to Course Branchedour Valtage	V _{GS} = 0 V, I _D = 1 mA	600			V
BV_{DSS}	BV _{DSS} Drain to Source Breakdown Voltage	V _{GS} = 0 V, I _D = 1 mA, T _J = 150°C	650			
	7 0 1 1/1 5 1 0 1	V _{DS} = 600 V, V _{GS} = 0 V			10	
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 480 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 125^{\circ}\text{C}$		20		μA
$I_{\rm GSS}$	Gate-Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA
On Chara	cteristics					
V _{GS(th)}	Gate Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 2.1 \text{ mA}$	3.0		5.0	V
R _{DS(on)}	Static Drain to Source On Resistance	V _{GS} = 10 V, I _D = 15.3 A		89	105	mΩ
Dynamic	Characteristics					
C _{iss}	Input Capacitance	V _{DS} = 400 V, V _{GS} = 0V,		2176		pF
C _{oss}	Output Capacitance	f = 250 kHz		61		pF
C _{o(tr)}	Time Related Output Capacitance	V = 0.V/+= 400.V/ V = 0.V/		629		pF
C _{o(er)}	Energy Related Output Capacitance	$V_{DS} = 0 \text{ V to } 400 \text{ V}, V_{GS} = 0 \text{ V}$		96.3		pF
Q _{g(tot)}	Total Gate Charge at 10 V			53		nC
Q_{gs}	Gate to Source Charge	$V_{DS} = 400 \text{ V}, I_{D} = 15.3 \text{ A},$ $V_{GS} = 10 \text{ V}$		13.2		nC
Q_{gd}	Gate to Drain "Miller" Charge	1 65		27		nC
R_{G}	Gate Resistance	f = 1 MHz		1		Ω
Switching	Characteristics					
t _{d(on)}	Turn-On Delay Time			21		ns
t _r	Turn-On Rise Time	$V_{DS} = 400 \text{ V}, I_{D} = 15.3 \text{ A},$		13		ns
$t_{d(off)}$	Turn-Off Delay Time	V_{GS} = 10 V, R _G = 10 Ω See Figure 13		74		ns
t _f	Turn-Off Fall Time			9		ns
Source-D	rain Diode Characteristics					
I _S	Maximum Continuous Diode Forward Current				31.5	Α
I _{SM}	Maximum Pulsed Diode Forward Curren	t			94.5	Α
V _{SD}	Diode Forward Voltage	V _{GS} = 0 V, I _{SD} = 15.3 A			1.2	V
t _{rr}	Reverse Recovery Time	V _{DD} = 400 V, I _{SD} = 15.3 A,		114		ns
Q _{rr}	Reverse Recovery Charge	dl _F /dt = 100 A/µs		0.66		μC

※Notes:

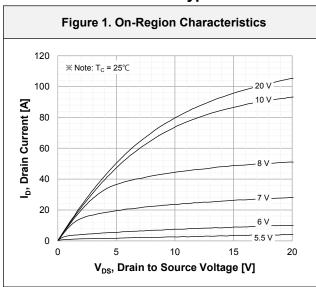
- Repetitive rating: pulse-width limited by maximum junction temperature.
- I_{AS} = 5.4 A, R_{G} = 25 Ω , starting T_{J} = 25 $^{\circ}$ C. I_{SD} ≤ 15.3 A, di/dt ≤ 100 A/ μ s, V_{DD} ≤ 400 V, starting T_{J} = 25 $^{\circ}$ C.

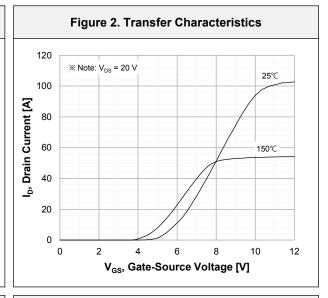


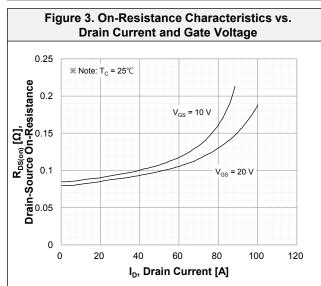
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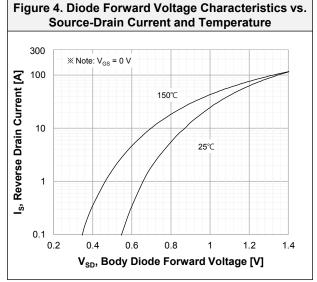


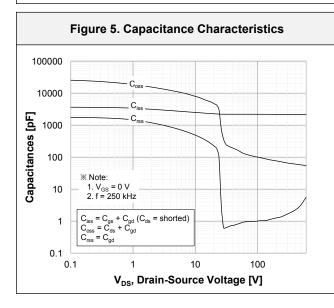
Typical Performance Characteristics

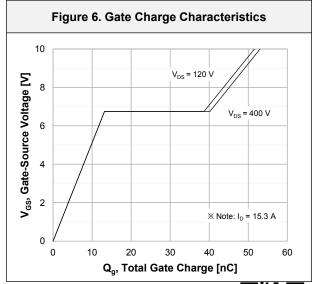










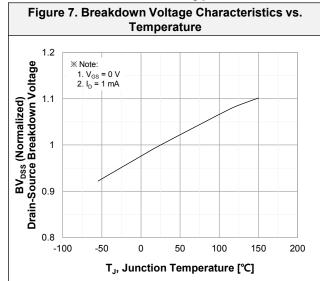


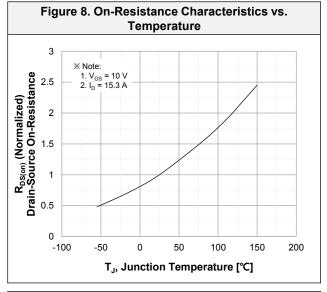
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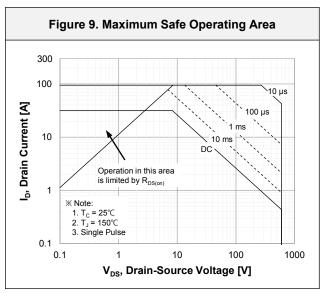


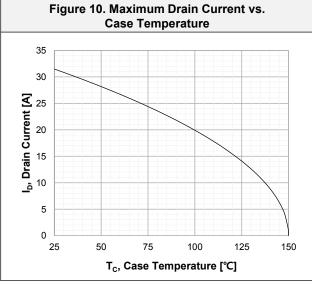
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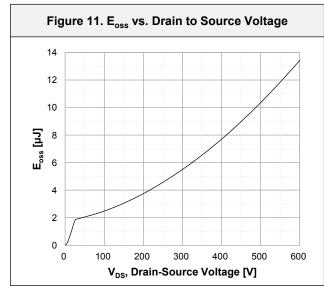
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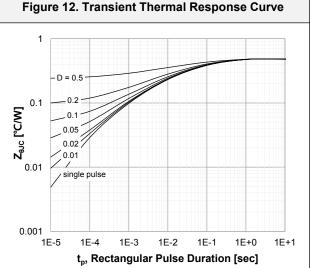














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Test Circuits

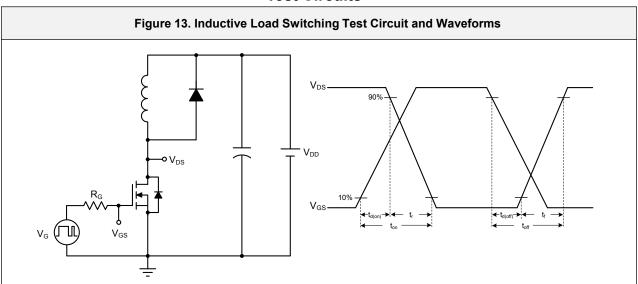
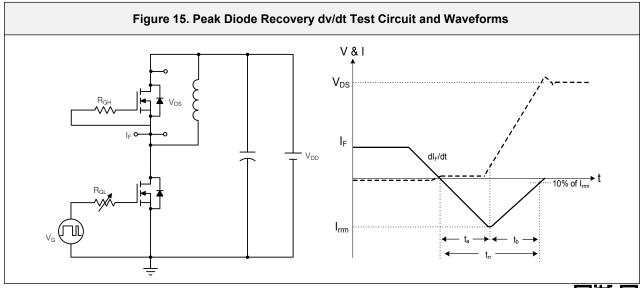


Figure 14. Unclamped Inductive Switching Test Circuit and Waveforms $\mathsf{BV}_{\mathsf{DSS}}$ V_{DD}

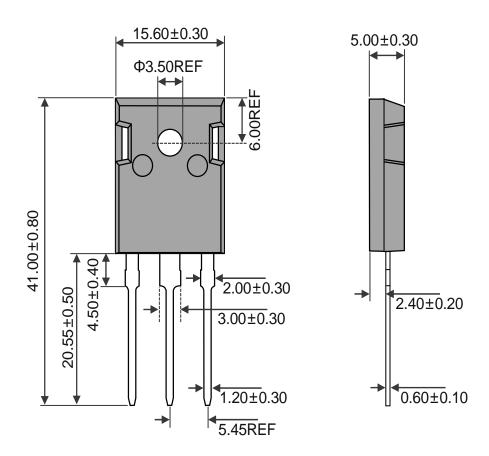






Package Outlines

TO-247AB



TO-247AB Unit:mm







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